

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | | Symbol | Value | Units |
|---|------------------------|--------------|------------------------|------------------|-------|-------|
| Drain-Source Voltage | | | | V _{DSS} | 20 | V |
| Gate-Source Voltage | | | | V _{GSS} | ±12 | V |
| Continuous Drain Current (Note 5) | V _{GS} = 10V | Steady State | T _A = +25°C | I _D | 5.4 | A |
| | | | T _A = +70°C | | 4.3 | |
| Continuous Drain Current (Note 5) | V _{GS} = 2.5V | Steady State | T _A = +25°C | I _D | 4.6 | A |
| | | | T _A = +70°C | | 3.7 | |
| Continuous Body Diode Forward Current (Note 5) | | Steady Stat | T _A = +25°C | I _S | 0.9 | A |
| Pulsed Drain Current (Note 5) 10μs pulse, duty cycle = 1% | | | | I _{DM} | 30 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units |
|--|-----------------------------------|-------------|-------|
| Total Power Dissipation (Note 5) | P _D | 0.78 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 161 | °C/W |
| Thermal Resistance, Junction to Case (Note 5) | R _{θJC} | 26 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---------------------|------|------|------|------|---|
| OFF CHARACTERISTICS (Note 6) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | - | - | V | V _{GS} = 0V, I _D = 250μA |
| Zero Gate Voltage Drain Current | I _{DSS} | - | - | 1.0 | μA | V _{DS} = 20V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | - | - | 10 | μA | V _{GS} = ±10V, V _{DS} = 0V |
| Gate-Source Breakdown Voltage | BV _{SGS} | ±12 | - | - | V | V _{DS} = 0V, I _G = ±250μA |
| ON CHARACTERISTICS (Note 6) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.35 | - | 0.95 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance | R _{DS(on)} | - | 15.5 | 18.5 | mΩ | V _{GS} = 10V, I _D = 7A |
| | | - | 16.5 | 21 | | V _{GS} = 4.5V, I _D = 7A |
| | | - | 17 | 21.5 | | V _{GS} = 4.0V, I _D = 7A |
| | | - | 17.5 | 22.5 | | V _{GS} = 3.6V, I _D = 6.5A |
| | | - | 18 | 23 | | V _{GS} = 3.1V, I _D = 6.5A |
| | | - | 19 | 24 | | V _{GS} = 2.5V, I _D = 5.5A |
| | | - | 24 | 31 | | V _{GS} = 1.8V, I _D = 3.5A |
| | | - | - | - | | - |
| Forward Transfer Admittance | Y _{fs} | - | 13 | - | S | V _{DS} = 5V, I _D = 5A |
| Diode Forward Voltage | V _{SD} | - | 0.7 | 1.0 | V | V _{GS} = 0V, I _S = 1A |
| DYNAMIC CHARACTERISTICS (Note 7) | | | | | | |
| Input Capacitance | C _{iss} | - | 143 | - | pF | V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz |
| Output Capacitance | C _{oss} | - | 74 | - | pF | |
| Reverse Transfer Capacitance | C _{rss} | - | 29 | - | pF | |
| Gate Resistance | R _g | - | 202 | - | Ω | V _{DS} = 0V, V _{GS} = 0V, f = 1MHz |
| Total Gate Charge | Q _g | - | 8.8 | - | nC | V _{GS} = 4.5V, V _{DS} = 10V, I _D = 6.5A |
| Gate-Source Charge | Q _{gs} | - | 1.4 | - | nC | |
| Gate-Drain Charge | Q _{gd} | - | 3.0 | - | nC | |
| Turn-On Delay Time | t _{D(on)} | - | 53 | - | ns | V _{DD} = 10V, V _{GS} = 4.5V, R _L = 10Ω, R _G = 6Ω |
| Turn-On Rise Time | t _r | - | 78 | - | ns | |
| Turn-Off Delay Time | t _{D(off)} | - | 562 | - | ns | |
| Turn-Off Fall Time | t _f | - | 234 | - | ns | |

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to product testing.

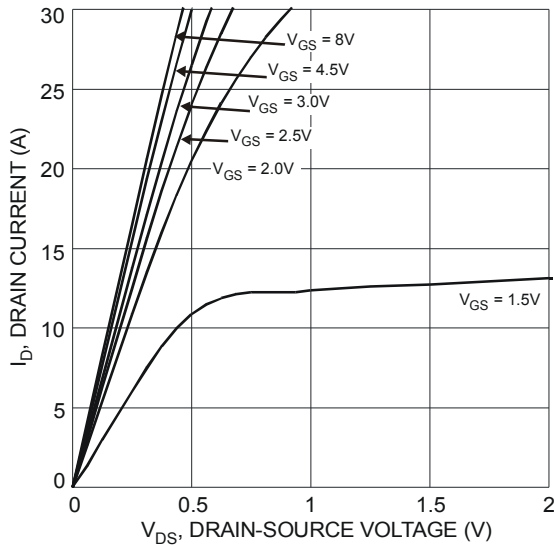


Fig. 1 Typical Output Characteristic

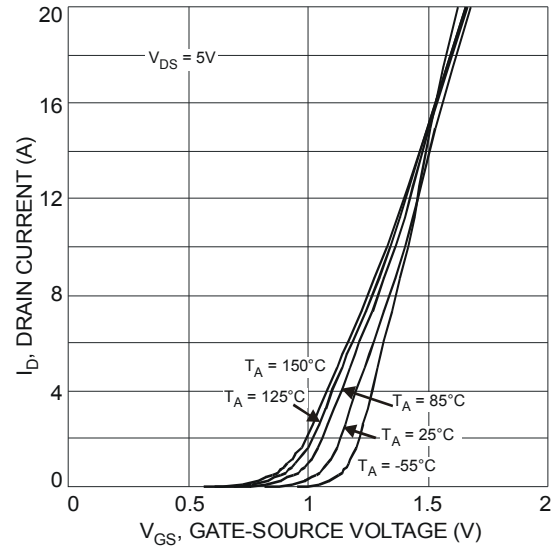


Fig. 2 Typical Transfer Characteristic

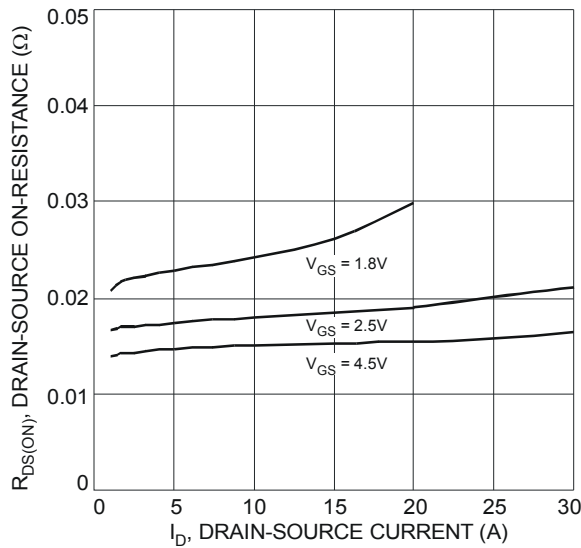


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

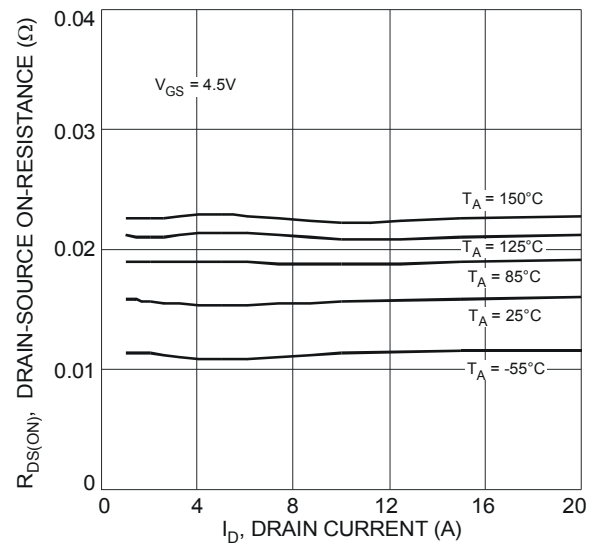


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

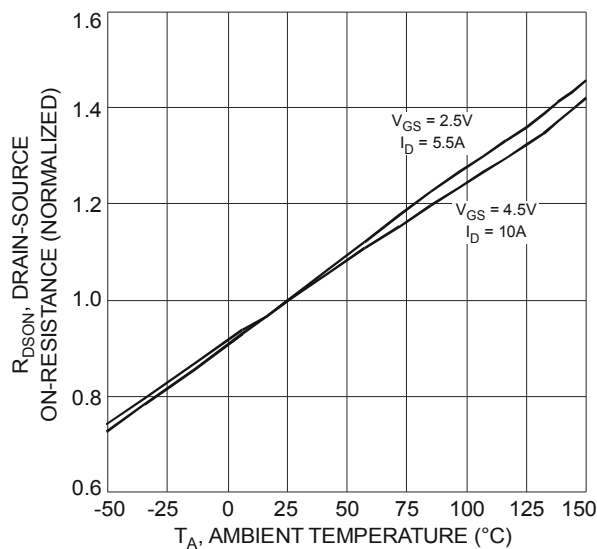


Fig. 5 On-Resistance Variation with Temperature

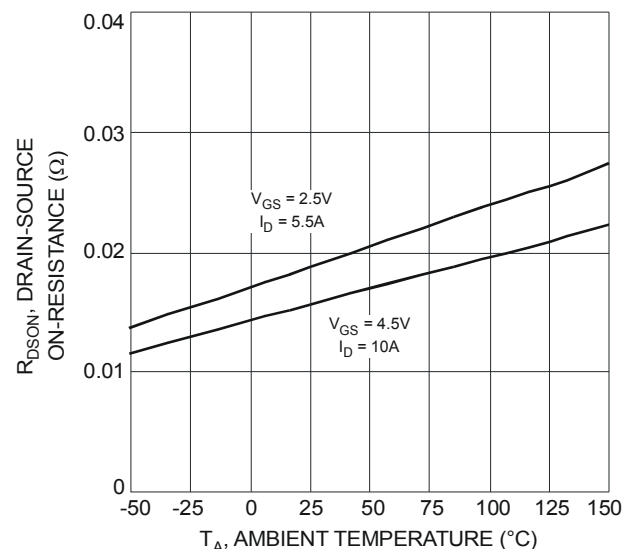


Fig. 6 On-Resistance Variation with Temperature

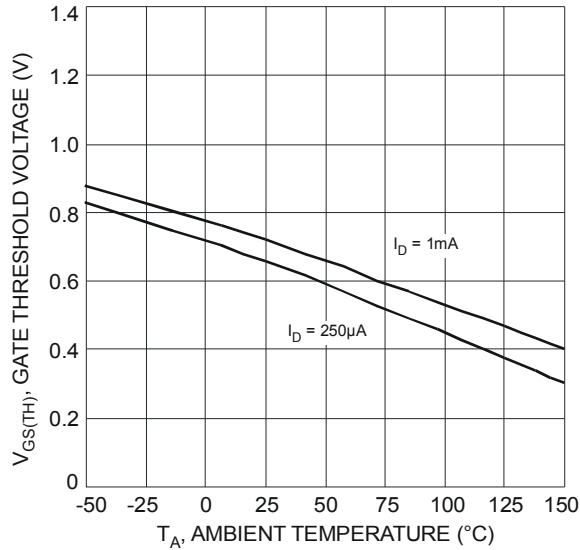


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

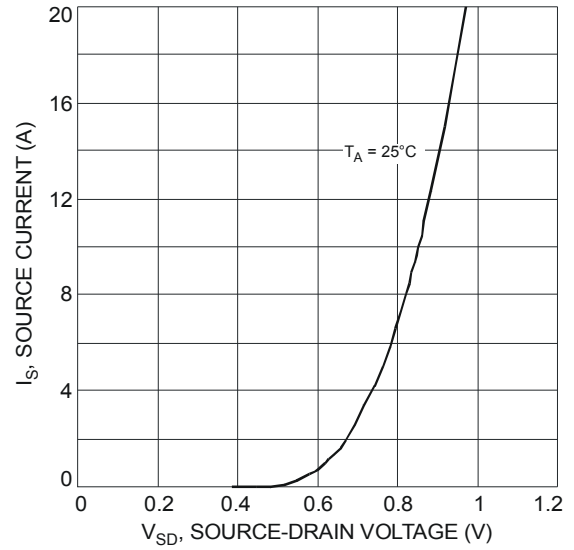


Fig. 8 Diode Forward Voltage vs. Current

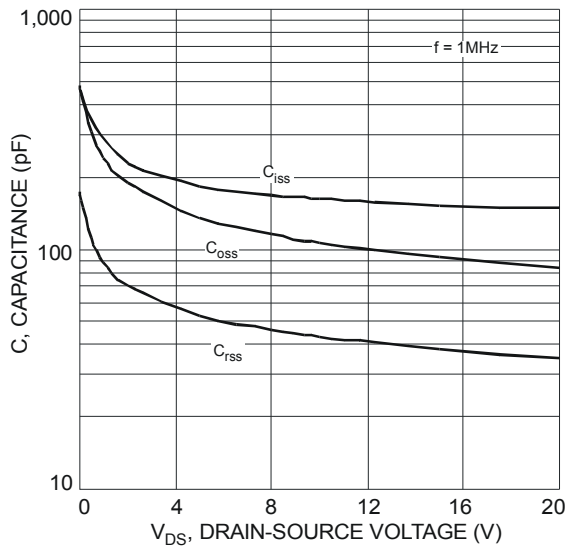


Fig. 9 Typical Total Capacitance

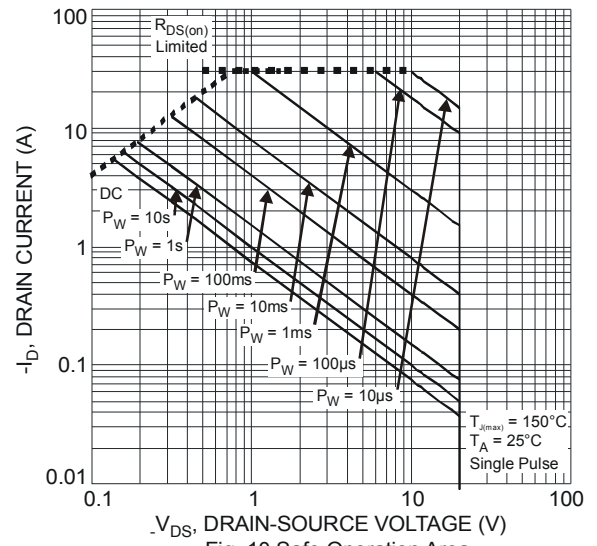


Fig. 10 Safe Operation Area

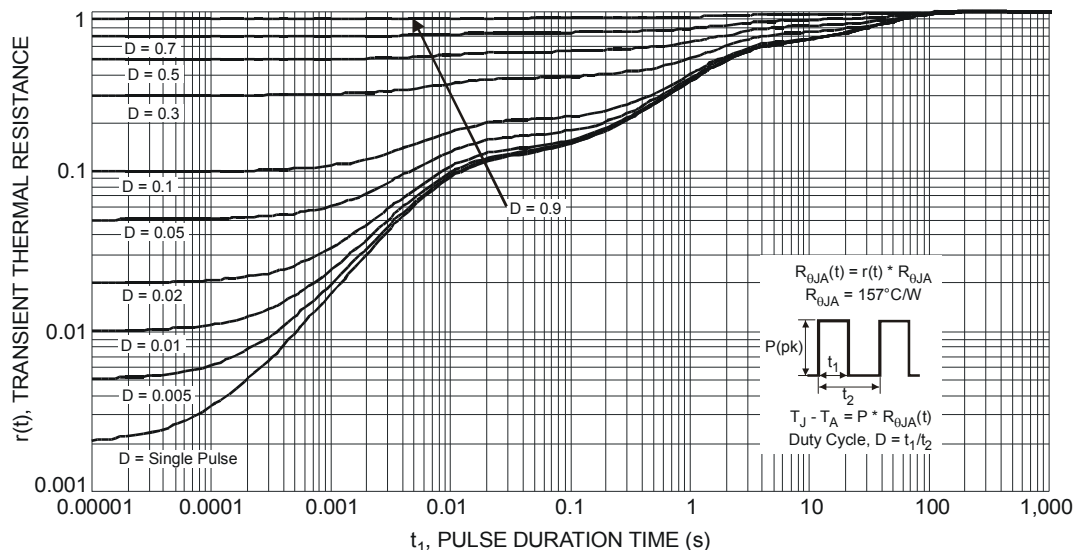
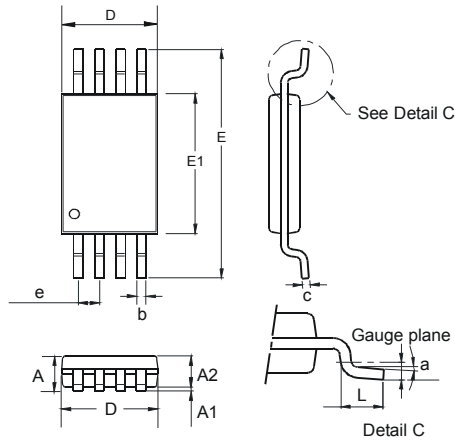


Fig. 11 Transient Thermal Response

Package Outline Dimensions

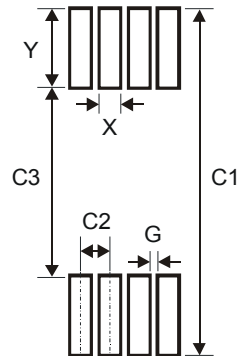
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| TSSOP-8 | | | |
|----------------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| a | 0.09 | — | — |
| A | — | 1.20 | — |
| A1 | 0.05 | 0.15 | — |
| A2 | 0.825 | 1.025 | 0.925 |
| b | 0.19 | 0.30 | — |
| c | 0.09 | 0.20 | — |
| D | 2.90 | 3.10 | 3.025 |
| e | — | — | 0.65 |
| E | — | — | 6.40 |
| E1 | 4.30 | 4.50 | 4.425 |
| L | 0.45 | 0.75 | 0.60 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| X | 0.45 |
| Y | 1.78 |
| C1 | 7.72 |
| C2 | 0.65 |
| C3 | 4.16 |
| G | 0.20 |

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